HALOGEN FREE



Vishay General Semiconductor

Photovoltaic Solar Cell Protection Schottky Rectifier

Ultra Low $V_F = 0.30 \text{ V}$ at $I_F = 5.0 \text{ A}$



PRIMARY CHARACTERISTICS				
I _{F(AV)}	20 A			
V_{RRM}	45 V			
I _{FSM}	250 A			
V_F at $I_F = 20 A$	0.42 V			
T _{OP} max. (AC mode)	150 °C			
T _J max. (DC forward current)	230 °C			
Package	P600			
Diode variation	Single die			

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- High forward surge capability
- · ESD capability
- High junction temperature 230 °C maximum at DC forward current
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: For definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

MECHANICAL DATA

Case: P600

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test **Polarity:** Color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	VSB2045Y	UNIT		
Device marking code		V2045Y			
Maximum repetitive peak reverse voltage	V _{RRM}	45	V		
Maximum average forward rectified current (fig. 1)	I _{F(DC)} (1)	20	A		
	I _{F(DC)} (2)	6.5	A		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	250	А		
Operating junction temperature range	T _{OP}	-40 to +150	°C		
Storage temperature range	T _{STG}	-40 to +175	°C		
Junction temperature in DC forward current without reverse bias, $t \le 1 \ h$	T _J ⁽¹⁾	≤ 230	°C		

Notes

- (1) With heatsink
- (2) Without heatsink, free air



Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage	I _F = 5.0 A	T _A = 25 °C	V _F ⁽¹⁾	0.44	=	V	
	I _F = 10 A			0.46	-		
	I _F = 20 A			0.50	0.58		
	I _F = 5.0 A	T _A = 125 °C		0.30	-		
	I _F = 10 A		T _A = 125 °C		0.35	-	
	I _F = 20 A			0.42	0.50		
Reverse current	V _R = 45 V	T _A = 25 °C T _A = 125 °C	T _A = 25 °C	I _R ⁽²⁾	23.4	1200	μΑ
	v _R = 45 v		'R (=)	11.9	35	mA	
Typical junction capacitance	4.0 V, 1 MHz		CJ	2050	-	pF	

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: 40 ms pulse width

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER SYM		VSB2045Y	UNIT	
Thermal resistance	R _{θJA} ⁽¹⁾	55	°C/W	
	R _{0JL} (1)	3.5	C/VV	
Typical thermal resistance	R _{0JL} (2)	2.5	°C/W	

Notes

(1) Without heatsink, free air; units mounted on PCB with 2 mm x 2 mm copper pad areas at 9.5 mm lead length

 $^{^{(2)}}$ Leads clipped at 3 mm lead length from plastic body on 7.0 cm x 2.2 cm x 1.9 cm x 2 heatsink

IMMUNITY TO ELECTRICAL STATIC DISCHARGE TO THE FOLLOWING STANDARDS ($T_A = 25~^{\circ}\text{C}$ unless otherwise noted)					
STANDARD	ARD TEST TYPE TEST CONDITIONS SYMBOL CLASS V.				VALUE
JESD22-A114	Human body model (contact mode)	C = 150 pF, R = 1.5 Ω		3B	> 8 kV
JESD22-A115	Machine model (contact mode)	C = 200 pF, R = 0 Ω	V_{C}	С	> 400 V
IEC 61000-4-2 (2)	Human body model (air discharge mode) (1)	C = 150 pF, R = 330 Ω		4	> 15 kV

Notes

(1) Immunity to IEC 61000-4-2 air discharge mode has a typical performance > 25 kV

⁽²⁾ System ESD standard

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
VSB2045Y-M3/54	1.88	54	800	13" diameter paper tape and reel		
VSB2045Y-M3/73	1.88	73	300	Ammo pack packaging		



Vishay General Semiconductor

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

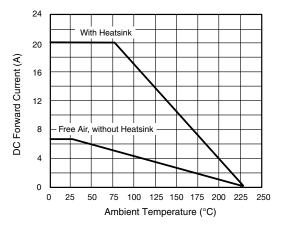


Fig. 1 - Forward Current Derating Curve

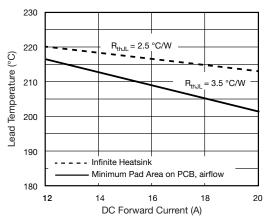


Fig. 2 - Rated Forward Current vs. Ambient Temperature

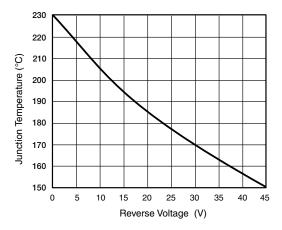


Fig. 3 - Forward Power Loss Characteristics

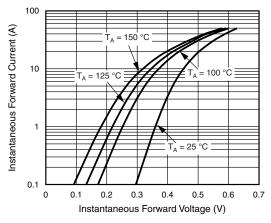


Fig. 4 - Typical Instantaneous Forward Characteristics

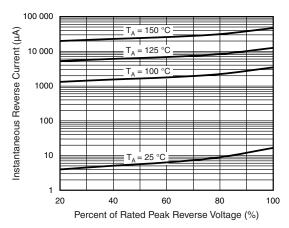


Fig. 5 - Typical Reverse Leakage Characteristics

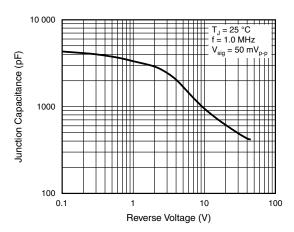
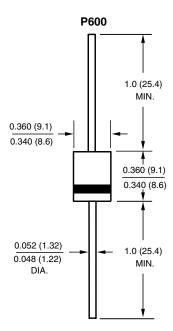


Fig. 6 - Typical Junction Capacitance

Vishay General Semiconductor

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by Vishay manufacturer:

Other Similar products are found below:

MA4E2039 D1FH3-5063 MBR10100CT-BP MBR1545CT MMBD301M3T5G RB160M-50TR RB551V-30 BAS16E6433HTMA1 BAT
54-02LRH E6327 NSR05F40QNXT5G NTE555 JANS1N6640 SB07-03C-TB-H SB1003M3-TL-W SK310-T SK32A-LTP SK33A-TP
SK34B-TP SS3003CH-TL-E GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRB30H30CT-1G SB007-03C-TB-E SK32A-TP
SK33B-TP SK35A-TP SK38B-TP NRVBM120LT1G NTE505 NTSB30U100CT-1G SS15E-TP VS-6CWQ10FNHM3 ACDBA1100LR-HF
ACDBA1200-HF ACDBA140-HF ACDBA2100-HF ACDBA3100-HF CDBQC0530L-HF CDBQC0240LR-HF ACDBA340-HF
ACDBA260LR-HF ACDBA1100-HF SK310B-TP MA4E2502L-1246 MA4E2502H-1246 NRVBM120ET1G NSR01L30MXT5G NTE573
NTE6081